

**Dimensional Dependence of Light Interaction with Nanowires**

A Thesis

Submitted to the Faculty

of

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by

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in partial fulfillment of the

requirements for the degree

of

Doctor of Philosophy

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## DEDICATIONS

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This thesis is dedicated to my family. Their unconditional support and love was the foundation of success for my graduate study. I want you to know that I love you so much and this thesis was only possible thanks to you. \_\_\_\_\_

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## ACKNOWLEDGMENTS

This work would not have been possible without the support of my advisor, Dr. Bahram Nabet. His guidance helped to shape and provided much needed focus to my work. I would like to thank my dissertation committee of Dr. Timothy Kurzweg, Dr. Baris Taskin, Dr. Nagarajan Kandasamy, and Dr. Goran Karapetrov for their support and insight throughout my research.

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## ABSTRACT

Dimensional Dependence of Light Interaction with Nanowires

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Semiconductor nanowires have been used in a variety of passive and active optoelectronic devices including waveguides, photodetectors, solar cells, LEDs, Lasers, sensors, and optical antennas. We review the optical properties of these nanowires in terms of absorption, guiding, and radiation of light, which may be termed light management. Analysis of the interaction of light with long cylindrical structures with sub-wavelength diameters identifies radial resonant modes, such as Leaky Mode Resonances, or Whispering Gallery modes. The two-dimensional treatment should incorporate axial variations in volumetric modes which have so far been presented in terms of Fabry-Perot, and Helical resonance modes. We report on FDTD simulations with the aim of identifying the dependence of these modes on: geometry (length, width), tapering, shape (cylindrical, hexagonal), core-shell versus core-only, and dielectric cores with semiconductor shells. This demonstrates how NWs form excellent optical cavities without the need for top and bottom mirrors. However, optically equivalent structures such as hexagonal and cylindrical wires can have very different optoelectronic properties meaning that light management alone does not sufficiently describe the observed enhancement in upward (absorption) and downward transitions (emission) of light in nanowires; rather, the electronic transition rates should be considered. We discuss this rate-management scheme showing its strong dimensional dependence, making a case for photonic integrated circuits that can take advantage of the confluence of the desirable optical and electronic properties of these nanostructures.



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## CHAPTER 1

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### INTRODUCTION

#### 1.1 Background

#### 1.2 Problem Statement

#### 1.3 Literature Review

#### 1.4 Outline of Chapters

This thesis is structured as follows. The data used for this analysis are presented in Chapter 2. After introducing the corrections and data analysis methods, Chapter ?? presents our findings for individual and mean bolometric corrections. Chapter ?? presents our methods and findings for estimating dust reddening associated with a subset of our quasars. The statistical methods used in this chapter are outlined in more detail in Appendix A. In Chapter ??, we apply the corrections from Chapter ?? to our SEDs and use estimated black hole masses to study changes in the SEDs with the properties of the central black hole. Finally, we present our conclusions in Chapter 6. Throughout this work we use a  $\Lambda$ CDM cosmology with  $H_0 = 71 \text{ km s}^{-1} \text{ Mpc}^{-1}$ ,  $\Omega_\Lambda = 0.734$ , and  $\Omega_m = 0.266$ , consistent with the *Wilkinson Microwave Anisotropy Probe* 7 cosmology<sup>1</sup>.

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## CHAPTER 2

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# OPTICAL ENHANCEMENT OF CORE-SHELL NANOWIRE

## 2.1 Growth of Nanowires

## 2.2 Scanning Electron Microscopy Images

Figure 1a is top view SEM image of nanowires of 100nm diameter core of GaAs, and 40nm thick AlGaAs, with the inset showing a magnified image that demonstrates the rather sparse distribution of the wires. Figure 1b shows the reflectivity of a GaAs wafer on which 50nm thin film of AlGaAs is grown, and compares this to the reflectivity spectrum of a Si substrate. As expected, about 30% bulk Si and GaAs, with a sharp change for wavelengths near their respective band gaps. Figure 1c contrasts this with the measured absorption spectrum of two types of GaAs core, AlGaAs shell (CS) nanowires (BW): those grown on a GaAs substrate (black), and the others heteroepitaxially grown on a Si substrate (red). The spectra show that both cases have the signature change of reflectivity at bandgap of GaAs, i.e., these are due to the GaAs/AlGaAs CSNWs, not the substrate. Importantly, for the wavelength range of 700-1200nm these core-shells which only occupy 15% of the volume compared to thin films of the same height, reflect 2-4% of light for those grown on GaAs substrate. The beam-width of the incident light being 1mm, this shows that only a few NWs are interrogated by light and, normalized to volume, these wires absorb more than two orders of magnitude more light than their thin-film counterparts.

## 2.3 Electrical Characterization of Nanowire

## 2.4 Absorption Enhancement

## 2.5 Emission Enhancement

## 2.6 Lasing

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## CHAPTER 3

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# LIGHT CONFINEMENT IN SUB-WAVELENGTH NANO-STRUCTURE

### 3.1 Light and Nanowire

#### 3.1.1 Leaky Mode Resonance

Interaction of light with a dielectric or metallic cylindrical medium is analyzed by solving Maxwell's equations with the appropriate boundary conditions in the classical waveguide theory [80] which leads to highly confined modes in optical fibers and microscale dielectric resonators. In an infinitely long cylinder, even at deep sub-wavelength diameters this results in a characteristic equation the solution to which are the transverse magnetic (TM) and transverse electric (TE) resonant modes. We can define the electromagnetic modes of localized resonators as time-harmonic solutions of the form to the source-free Maxwell equations. This solution shows that the longitudinal field component distributes outside the NW, and is in resonance with the natural modes, such as TE<sub>11</sub>, TM<sub>02</sub>, etc., supported by the NW. These modes have been termed leaky-mode resonances (LMR) [81, 82], and provide an intuitive tool to facilitate the understanding and optimization of the resonance effect in such nano-structures. We replicate these results using MEEP, a widely used open-source finite-difference time-domain (FDTD) simulation package [83], to identify how light is confined in an infinitely long GaAs nanowire. The top row of Fig. 1 shows several configurations of TM LMR modes for a NW with diameter of 220nm, with excitation single wavelength light being incident parallel to the NW axis. The blue and red color codes represent the polarization of the electric fields. The TE modes are primarily identical to the TM modes shown here with the electric and magnetic fields

exchanged. If the light is incident with an arbitrary angle, then so-called hybrid HE and EH leaky modes will be excited instead of the pure TE or TM mode. The bottom row of Fig. 1 shows the directional energy flux density of the electromagnetic field, the Poynting vector, at different time frames with light being incident perpendicular to the NW axis from the right side. The light is seen to propagate from the right and then mostly remain confined at the left part of the cylinder. It is notable that in either case the light energy is spatially distributed along the cross section of the wire but, as expected from a 2D treatment does not vary axially. Figure 1 demonstrates that the LMR can gently confine light within subwavelength semiconductor nano-structures, similar to the intuitive ray-optics picture of multiple total internal reflections from the periphery of the cylinder. As shown by in Ref. [81], these LMRs depend on the radius and the height of the dielectric, which allows light engineering of the nanowires so as to increase its absorption efficiency at pre-determined wavelength, e.g., to maximize absorption of sunlight spectrum for higher efficiency solar cells, or to radiate as optical antennas.

### 3.1.2 Whispering Gallery Modes

Infinitely long cylindrical or hexagonal NW structures can also support Whispering Gallery (WG) modes [78, 79, 84-90]. To calculate the resonant WGMs, Maxwells equations have to be solved numerically [91] taking into consideration the spectral dependence of the material of interests index of refraction. However, we can deduce a simple plane-wave model from theoretical derivations, and the relationship between resonance wavelength and the corresponding mode serial number  $N$  can be obtained [92]. The WG modes can also reflect and confine light in the (subwavelength) nanostructure by total internal reflection from the curvature of the structure boundaries. However, a light wave can interfere with itself only when having completed one full circulation within the resonator, which means only the light with one or multiple wavelengths are allowed to perform multiple circulations generating a standing wave. Figure 2 from reference 85 shows near-field intensity patterns of low-order TM polarized hexagonal WGMs for  $n=1$  and refractive index  $=2.1$ . Each mode pattern is labeled by its respective mode number  $m$  (lower right number) and its symmetry class (upper right

symbol). For comparison, four mode patterns of the circular cavity are given in the upper left and lower right together with their angular mode number. We again observe the radial spatial dependence of light intensity. Furthermore, the low order WG modes of hexagonal NWs are essentially similar to the cylindrical ones, but for higher order modes additional features will arise on the facets of the hexagonal NWs [85]. Simulation results also show little difference between WG mode and Leaky modes in lower order modes for both hexagonal and cylindrical structures. As with the LMR, the resonant WG modes have been used as the basis for a precise theoretical explanation of the enhanced optical behavior of hexagonal NWs, such as enhanced light absorption [81, 93-96] and emission [78, 97-99]. Furthermore, these numerical solutions have lead to reproduction of experimental resonance spectra, e.g., polarization-resolved micro-photoluminescence (-PL) and cathodeluminescence (CL) spectroscopy.

### 3.1.3 Fabry-Perot Resonant Mode

The above analysis and results apply to long structures, hence, provide two-dimensional radial modes, independent of the NW axis. However, light confinement has strong axial dependence, necessitating three-dimensional analysis of the cavity modes. FDTD simulation in 3D are used to identify the axial dependence of resonant modes in these nano-structures, revealing modes which are volumetric in nature. Fabry-Perot (FP) modes have been analyzed for sub-microcavity, or nano-cavity, NWs with cylindrical or hexagonal structures, specifically in order to determine the axial dependence of the resonance modes [100]. At least two mirrors are needed to construct the reflection structure inside the cavity, whether they are the top and bottom ends, i.e., the air and substrate interfaces with the nanowire, or any of the two opposite facets along the nanowire axis. For subwavelength structures, the longitudinal WG modes have high scattering losses due to diffraction, and axial FP waveguide modes will dominate [90]. However, due to small difference of the refractive index between the substrate and the nanowire dielectric, the existence of the FP mode will only be valid if the nanowire has relatively large radii, e.g., larger than 200 nm [101]. Under these conditions, besides the top and bottom ends, the lateral facets of nanowire can also be treated as two parallel



slabs, and with the dielectric in between, it can support the FP mode with mode spacing inversely related to the nanowire length. An application of this analysis is in the design of NW lasers, since the optical cavity modes are observed at threshold for lasing, and have been investigated for both optical and electrical pumped cases [102, 103]. As a results the FP resonance mode based nanoscale lasers are not only capable of covering a wide spectral regions, but can also can be integrated as single or multi-color laser source arrays in silicon based photonic integrated circuit or microelectronic devices [102,103]. However, the FP modes supported by the nano-cavity structure have relatively small quality factor due to the small difference of the refractive indices of the substrate and the NWs. In order to address this issue, Bragg gratings can be produced at the NW ends, alternatively, NWs can be placed on metal substrates in order to increase the FP resonance peak intensity by more than one order of magnitude compared to those on Si substrates [104].

### 3.1.4 Helical Resonance Modes

Nano needles of III-V material grown on heterogeneous substrates are optoelectronic devices which have shown interesting optical behavior, including lasing, at room temperature [105]. Figure 3 (A) shows SEM image of a nano-laser grown on silicon substrate that has subwavelength dimensions on all sides. Analysis of light propagation introduced by shows that unlike the traditional WG mode that lack vertical structure, there is net propagation in axial direction in these structures which leads to volumetric resonant modes which are termed helical mode resonances [105]. The schematic Fig. 3(B) suggests a helical ray path with nearly total internal reflection at the nanopillar-silicon interface due to the glancing angle of incidence from the hexagonal facets of the nano-laser shown in Fig. 3(A). As such, the faceted shape of the structure affects the optical cavity properties. FDTD-simulated field profile shows a hexagonal WG-like mode pattern in the transverseplane as in Fig. 3 (C), which arises from strong azimuthal components of helical modes. Figure 3 (D) shows first-order and higher-order standing waves axial variation. The radial mode number (first number,  $m$ ) describes the transverse field pattern for WG modes, and the axial mode number (second number,  $n$ ) describes the axial standing wave as is the case for Fabry-Perot resonances. It is seen that

light or optical field can be well confined in the nanostructure even with low index contrast at the dielectric interface thus producing the nano-resonators needed for lasing. Although the quality (Q) factors of such nanostructure are usually not large, these helically propagating cavity modes, provide an optical feedback mechanism without the sophisticated mirror structures of the vertical cavity surface emitting lasers (VCSELs). Additionally, since the nanowires are heteroepitaxially grown on different substrates, they enable heterogeneous integration of photonic emitters and silicon based computational circuitry. Whereas traditional FP modes are inhibited by the interface between semiconductor nanostructure and the silicon substrate, such unique optical structures have been proposed as an avenue for engineering and integrating on-chip nanophotonic devices.

### 3.2 Volumetric Modes

The diameter of the nanostructures which can support the helical resonance modes is near the Rayleigh limit, around the boundary of the validity of ray-optics. FDTD analysis can be applied to deeper subwavelength structure in order to identify the cavity modes which are by nature volumetric, i.e., axially dependent. Figure 4 shows simulation results for various diameters of hexagonal structure of 1  $\mu\text{m}$  length. Incident radiation with 532 nm wavelength is nearly parallel to the wire axis and different modes are displayed for different radii. Top row shows radial spatial dependence at the middle of the wire axis, and the bottom row shows the axial dependence. Top row results are similar to Figures 1-2, and the bottom row shows that the light can be confined in volumetric resonance mode in both transverse plane and longitudinal plane even with sub-wavelength diameter of these hexagonal NWs. Unlike helical modes, the explanation of resonance need not rely on an intuitive ray-optics description based on the grazing angle of incident light, but shows similar results in how the deep subwavelength structures can confine the light and produce a resonant cavity without having sophisticated mirrors at the end facets. In this respect nano-cavities of as-grown nanowires outperform microcavities of VCSELs.

### 3.2.1 Nanocavity Geometry Dipendence

### 3.2.2 Light Engineering of Nanocavities

Dependence of the resonant modes on the cavity geometry offers an important degree of freedom to engineer a cavity for particular optical properties. Figure 6 shows the dependence of three volumetric TM resonant modes excitation wavelengths with radius. In this spectral range, only lower TM modes can be excited with smaller radii, e.g.,  $r = 40$  nm and 60 nm, however, as the radius increases, higher order modes can be excited, and the optical power corresponding to the lower order modes will be reduced. We observe redshift of these volumetric TM modes with increasing NW radius. Also, the wavelength variation of TM<sub>1n</sub> mode is much larger compared to TM<sub>2n</sub> and TM<sub>3n</sub> modes. These observations demonstrate the feasibility to engineer the volumetric mode at certain wavelength, i.e., allow us to optimize absorption or emission at a desired frequency or certain incident optical power by controlling the radius and/or length of a NW thus providing the ability to engineer the absorption spectrum in order to match desired properties.

The dependence of the resonant modes on NW radius also suggests the interesting possibility of having tapered structures which can support more than one resonant mode, thus be able to optimize the spectrum of interest. The metalorganic vapor phase epitaxy (MOVPE) or vapor liquid solid (VLS) growth methods are readily capable of forming nanowires with tapered sidewalls. The resultant cavity, however, does not support the superposition of the modes present in cylindrical structures of the same diameter; in fact tapered sidewalls have been identified as the primary loss mechanism for these sub-wavelength cavities. The effect of tapering has been studied for nanopillars that were grown on a silicon substrate with average 5° angles between opposite sidewalls; vertical field profiles for  $\text{TM}_{10}$ ,  $\text{TM}_{20}$ , and  $\text{TM}_{30}$  modes are shown in Fig. 7 [105]. The modes are primarily confined at the base, and become less resonant as they propagate upwards with decreasing of the radius at top. Higher-order axial modes generally have lower quality factor. Physically, the stronger Fabry-Perot characteristic of higher-order axial modes means that their effective longitudinal wave-vector components become stronger, causing larger penetration and loss into the substrate. Nevertheless, from

a different perspective, multi-mode resonances can be achieved within certain wavelength range by controlling the tapering angle in order to form small varying radius along the nanostructure axial direction. One can also red- or blue-shift the resonance peaks, since these volumetric resonance modes are dependent on transverse dimensions. Thus, intentioned tapering offers an alternative way to engineering the multi-mode resonances and finer tunability of these resonance peaks.

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## CHAPTER 4

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### REDUCED ELECTRONIC DENSITY DISTRIBUTION

#### 4.1 Self-consistent Poisson-Schrodinger Solver

#### 4.2 Electronic Distribution in Nanowires

Figure 8 (C) shows the FDTD-simulated electric field density of a hexagonal nanowire at y cross section (top) and x cross section (bottom). The photon energy of this mode shown as the insets of Fig. 8(C) is concentrated primarily along the 6 corners and secondarily along the facets with little light in the 3D core of GaAs. Hence, we suggest that the fortuitous spatial overlap of the resonant optical modes on reduced dimensional electronic wavefunctions plays a significant role in the remarkable optoelectronic properties of core-shell nanowires. Restated, the superposition of the photon modes on reduced electronic states that form on the facets and vortices of the hexagonal CSNWs strongly enhances both upward and downward transition rates. Thus, the reduced dimensionality transition rate distinguishes the core-shell nanostructure from the optically equivalent structures of Fig. 6 due to its significantly modified rate management. These nanostructures are not only excellent optical cavities, but despite their large size also provide the right reduced dimensional electronic structures which enhance optoelectronic interactions. It should be noted the present analysis is for direct optical transitions; although it can be extended to incorporate k-vector changes as in phonon scattering, other important factors such as many-body interactions need to be included in a comprehensive analysis.

#### 4.2.1 Cylindrical Core-Shell Nanowire

#### 4.2.2 Hexagonal Core-shell Nanowire

#### 4.3 Conclusions

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## CHAPTER 5

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### DIMENSIONAL DEPENDENCE OF OPTICAL TRANSITION RATES

#### 5.1 Time-dependent Perturbation Theory

#### 5.2 Upward and Downward Transition Rates

#### 5.3 Contributing Factors

##### 5.3.1 Overlap Integral

##### 5.3.2 Oscillator Strength

##### 5.3.3 Joint Optical Density of States

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## CHAPTER 6

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### CONCLUSIONS AND FUTURE RESEARCH

As mentioned previously, communication of information, together with storage and computation form a grand challenge of the information age [2, 7]. Recently, the analysis of big data has become the engine for societal, financial, scientific, and technological endeavors. This demands an infrastructure that is capable of fast and reliable high volume data processing. Traditionally, this requirement was fulfilled by silicon technology. However, silicon-based technology has its own limitations, such as speed limit and heat dissipation problem. In order to process high volume data, we need data computation, storage and communication work as three fundamental functions of a computation cell. A monolithic nano-system may be envisioned which incorporates NWs as waveguides, detectors, photovoltaic cells, antennas, modulators, (photo)capacitors, LEDs, and lasers. These components may be incorporated in circuit layers, such as network on chip. Different layers can communicate using NW through-silicon vias (TSVs). Similar low-power/high-performance advantages can be realized through achievement of high interconnect densities on the 2.5D Through-Si-Interposer (TSI) as reported in [114]. In conclusion, optical properties of nano-cavities were reviewed here emphasizing the analysis of resonant optical modes which depend both radially and axially on the geometries of the nanowires. This shows how such sub-wavelength structures can form optical cavities as-grown, without needing sophisticated facet mirrors. In addition, we show how the fortuitous overlap of the reduced dimensional electronic wave functions and the photonic modes is responsible for the extraordinary optoelectronic properties of core-shell nanowires. Such nano-structures have been developed on heterogeneous substrates, particularly silicon, and as such becoming an important component in the next generation of photonic integrated circuits which are particularly useful in



meeting the grand challenge of low energy and fast speed computation.

## 6.1 Contributions of this dissertation

## 6.2 Outline of the future work

Low dimensional electron gases exist at the heterointerfaces of core-shell nanowires (CSNWs). For example, the GaAs/AlGaAs CSNWs typically form a hexagonal structure in which six (6) pillars of 1D charge at the vortices, and six (6) sheets of 2D charge at facets are formed [1]. At the same time, nanowires (NW) have also been shown to be capable of confining light in their sub-wavelength nano-structure, supporting photonic modes, and producing resonant cavities without the need for polished end facets. We have previously shown how the electronic wave functions that are thus formed affect the optical transition rates, resulting in orders of magnitude enhancement in absorption and emission of light [ref]. Here we report on the plasmonic effects of the confined charge on the optical properties of CSNWs. We report on finite difference time domain (FDTD) simulations with the aim of identifying the surface plasmon resonance modes which affect light confinement in hexagonal CSNWs, and help form a high quality factor resonant cavity. This is done by comparing regular CSNW, with a) wires covered with metal which produces surface plasmon-polaritons (SPP); b) NWs covered with metal that is sandwiched between the core and the outer, shell; and c) two-dimensional electron gas (2DEG) which is embedded at the heterointerface of CSNWs. Results show that the 2DEG behaves similarly to an embedded metallic surface, allowing for highly localized light confinement in these wires without the need for vertical structures such as Bragg mirrors commonly used in vertical cavity surface emitting lasers (VCSELs). Besides affecting the cavity, the 2DEG enhances the transition rates due to the plasmon-electron interaction, facilitating not only photonic stimulated emission and lasing, but also surface plasmon amplification by stimulated emission of radiation [2]. We model the dielectric function of the two dimensional electron gas using the Drude model for dispersive media, and extract its relevant parameters from [3]. The complex conductivity of the 2DEG is derived using the relaxation time approximation, effective reduced mass of electrons, and the density of the carriers in the gas. By substitution the complex conductivity in

Drude model, we can model the 2DEG, with given plasma frequency, damping coefficient, and the oscillator strength using FDTD simulator. The two dimensional plasma frequency is calculated as [3]:  $\omega_p = \sqrt{\frac{n e^2}{m^* \epsilon_0 \epsilon}}$  which, is the background dielectric constant and  $m^*$  is the effective mass of the electron. It is important to note that, as shown in (1), the plasma frequency of the 2DEG can be tuned with changing the carrier concentration. This tunability distinguishes the 2DEG from other plasmonic material such as metals. The complex conductivity of the electron gas is derived as [4]:

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## BIBLIOGRAPHY

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## APPENDIX A

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### TRANSITION RATES

This research project focuses on the dimensional dependence of the absorption behavior in semiconductor when interacting with light. Through time-dependent perturbation theory, we find out the transition rate and Fermis Golden Rule, then based on the light interaction Hamiltonian, time average Poynting vector and matrix element, derive the absorption coefficient for bulk semiconductor (3-dimension), quantum well (2-dimension) and quantum wire (1-dimension) structure. Finally, this report will discuss the partial confinement on the electron in the conduction band without the hole confined in the valence band situation.

The Schrodinger equation

The Hamiltonian  $H$  can be expressed as:

where  $H_0$  is the unperturbed part Hamiltonian and is time-independent,  $V$  is the small perturbation. The solution to the unperturbed part is assumed known

The time-dependent perturbation is assumed to have the form

Expand the wave function in terms of the unperturbed solution, we find out

gives the probability that the electron is in the state  $n$  at time  $t$ . Substituting the expansion for into Schrodinger equation and using (II.3), we have

Taking the inner product with the wave function  $\psi_n$ , and using the orthonormal property,

Therefore, the electron stays at the state  $i$  in the absence of any perturbation. The first order solution is

If we consider the photon energy to be near resonance, either or , we find the dominant terms: The absorption coefficient is a strong function of dimensionality. The confining situation of the quantum structure will considerably affect the energy levels, the overlap function of the conduction and valence band envelope function and also the joint optical density of state. Through the derivation of the absorption coefficient, we can observe the interaction between the light and semiconductor. The next questions should address: 1. The simulation data for single nanowire abs

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## VITA

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PLACE AND DATE OF BIRTH: Beijing, China — 15 August 1986  
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### WORK EXPERIENCE

<i>Present -</i> JUN 2015	BROOKHAVEN NATIONAL LABORATORY, Long Island, NY, US <i>Visiting Scientist</i> <ul style="list-style-type: none"> <li>• Performed SEM/TEM imaging of as-grown and dispersed core-shell nanowires in the clean room of center for fundamental nanomaterials.</li> <li>• Developed contacts of dispersed single nanowire by FIB, then characterized the device by I-V, C-V measurement and Photoluminescence spectroscopy.</li> </ul>
<i>Present -</i> MAR 2012	DREXEL UNIVERSITY, Philadelphia, PA, US <i>Graduate Research Fellow</i> <p>The focus of my research is on characterizing the extremely enhanced optical properties of core-shell nanowires and analyzing the fundamental mechanism of such significant enhancement in light absorption, emission and lasing behavior. Specifically optoelectronic characteristics and light-matter interactions of this novel nano-structure are in my interest. Meanwhile, I also participated in writing proposals for research grants from National Science Foundation, and for access permission to center for fundamental nanomaterials at Brookhaven National Lab.</p>
<i>Present -</i> MAR 2012	DREXEL UNIVERSITY, Philadelphia, PA, US <i>Teaching Assistant</i> <p>Involved dynamically in teaching responsibilities, e.g. running lectures, managing labs and carrying recitations and office hours in various courses including Electronic Devices, Analog Devices, Design for Microcontrollers, Digital Systems, Electrical Engineering Lab, Evaluation and Present Experimental Data, Linear and Dynamic Engineering System, and Statistic Analysis of Engineering System, Introduction to Physics.</p>
<i>Aug 2011 -</i> FEB 2011	IM FLASH SINGAPORE LLP., Singapore <i>(A Joint-Venture of Intel and Micron)</i> <i>Process Integration Engineer</i> <ul style="list-style-type: none"> <li>• Written analyze report for Special Work Requests and Global Conversion to align new process recipes and tools between Singapore and US.</li> <li>• Developed, maintained and improved a process module on an advance NAND Flash Memory including design rules for alternative flows.</li> <li>• Optimized existing process flows and developed creative solutions to meet product requirements.</li> <li>• Extracted, monitored, analyzed and reacted to inline data, param data and probe data to fix yield issues, add process margin and reduce costs.</li> </ul>

## EDUCATION

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<i>Present</i> -	<b>Drexel University</b> , Philadelphia, PA, US
SEP 2011	Doctor of Philosophy in ELECTRICAL ENGINEERING Research Field: <i>Solid State and Photonic Devices</i> — Advisor: Dr. Bahram NABET GPA: 3.93/4
<i>Dec 2010</i> -	<b>Nanyang Technological University</b> , Singapore
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<i>Jun 2009</i> -	<b>Huazhong University of Science and Technology</b> , Wuhan, China
SEP 2005	Bachelor of Engineering in COMMUNICATION ENGINEERING Thesis in Chinese: “Simulation of Wireless Streaming Media Distribution with Performance Evaluation” — Advisor: Dr. Xu DU GPA: 82/100

## AWARDS AND CERTIFICATES

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2011-PRESENT	Dean’s List for graduate students with an outstanding curriculum, Drexel University
JAN 2016	Allen Rothwarf Endowed Fellowship, Drexel University
OCT 2015	Graduate Student Domestic Travel Grant The Graduate College of Drexel University
SEP 2015	Finalist for Jean Bennett Memorial Student Travel Grant out of 200 applications, The Optical Society (OSA)
APR 2015	Best Poster Award of Drexel IEEE Graduate Forum’s 7 <sup>th</sup> Annual Research Poster Symposium
APR 2013	Best Student Poster in Physics, Drexel Research Day
NOV 2010	Best M.S. Dissertation, NTU
AUG 2009	Graduate Fellowship from Minister of Education of Singapore, NTU
MAY 2009	Best Engineering Undergraduate Thesis, Internet Technology and Engineering Research Center at HUST
OCT 2010	GRE®: 1430 (Q:800;V:630) 94 <sup>th</sup> percentile; AWA: 3.0/6.0

## PUBLICATIONS

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1. Z. Wang, B. Nabet, “Nanowire Optoelectronics” *Nanophotonics*, 4.1 (2015): -. Retrieved 17 Mar. 2016, from doi:10.1515/nanoph-2015-0025.
  2. Z. Wang, B. Nabet, “Interaction of Light with Low-Dimensional Nano-cavity Structure” Submitted to Physical Review Letter, 2015.
  3. Z. Wang, B. Nabet, “Light and Rate Management in Nanowires” in Frontiers in Optics 2015, OSA Technical Digest (online) (Optical Society of America, 2015), paper FW5C.6.
  4. Z. Wang, M. Currie, P. Prete, N. Lovergine, B. Nabet, “Lasing from As Grown GaAs-AlGaAs Core-Shell Nanowires up to Room Temperature” in Frontiers in Optics 2015, OSA Technical Digest (online) (Optical Society of America, 2015), paper LTh2I.4.
  5. Z. Wang, M. Currie, P. Prete, N. Lovergine, B. Nabet, “Room Temperature Lasing of GaAs-AlGaAs Core-Shell Nanowires Grown on Silicon Substrate” Accepted in proceeding of: 2<sup>nd</sup> EOS Topical Meeting on Optics at the Nanoscale (ONS15), At Capri, Italy. Sep 17-19, 2015.
  6. Z. Wang, M. Currie, P. Dianat, G. Konica, P. Prete, N. Lovergine, et al., “On Dimensional Dependence of Interaction of Light and Nano Structures,” In proceeding of: Frontiers in Optics, At Orlando, FL. Oct 10-12, 2013.

7. M. Currie, Z. Wang, P. Dianat, P. Prete, I. Miccoli, N. Lovergine, et al., "Large Light Emission Enhancement in GaAs/AlGaAs CoreShell Nanowires," In proceeding of: International Conference on One-Dimensional Nanomaterials, ICON2013, At Annecy, France. Sep, 2013.
8. Zhou, X., Zhu, G. J., Srikanth, M. K., Lin, S. H., Chen, Z. H., Zhang, J. B., ... & Wang, Z. (2010). Xsim: Benchmark Tests for the Unified DG/GAA MOSFET Compact Model. Proc. Nanotech, 2, 785-788.

## POSTER PRESENTATIONS & PANELS

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1. A Novel Alternative Infrastructure for Efficient High Volume Computation, Drexel IEEE Graduate Forums 7th Annual Research Poster Symposium, April, 2015.
2. Volumetric Optical Cavity Modes Allow Room Temperature GaAs/AlGaAs Core-Shell Nanowire Lasing, Drexel Research Day, April, 2014 & Nano for Business, Lehigh University, June, 2014.
3. As-grown GaAs/AlGaAs core-shell nanowire lase at room temperature, Drexel IEEE Forum, March, 2014.
4. Strong Photoluminescence Enhancement of Single GaAs/AlGaAs Core-Shell Nanowire, Drexel Research Day, April, 2013.

## LANGUAGES

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CHINESE: Native Proficiency  
 ENGLISH: Full Professional Proficiency  
 FRENCH: Basic Knowledge

## RESEARCH SKILLS

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Semiconductor Fabrication and Characterization:	Photoluminescence\Electroluminescence Spectroscopy, Scanning\Atomic\Tunneling Microscopy, THz Time-Domain Spectroscopy, Electron Beam Induced Current, Low and High-Temperature Electronic Probing and e-beam Lithography
Computer:	Microsoft Excel, Word, PowerPoint, PHP, MySQL, HTML, MATLAB, MEEP, Python, Adobe Photoshop and Illustrator, Sketchup, LINUX, ubuntu, L <sup>A</sup> T <sub>E</sub> X

## PROFESSIONAL & ACADEMIC MEMBERSHIP

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*Starting Jun 2015*    **OSA, Member**  
*Starting Jun 2015*    **APS, Member**  
*Starting Aug 2013*    **IEEE, Member**



## INTERESTS AND ACTIVITIES

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<i>Present -</i> AUG 2015	<b>Assistant Operation Officer, Drexel IEEE Graduate (DIG)</b> <ul style="list-style-type: none"> <li>• Served the Graduate IEEE community for contacting companies and academic professors for sponsorship and technical talks.</li> <li>• Organized and served as judge for Drexel IEEE Graduate Forum's 8<sup>th</sup> Annual Research Poster Symposium</li> </ul>
<i>Present -</i> AUG 2015	<b>First Drexel Diversity Council Advisory Board,</b> <b>Student Center for Inclusion and Culture (SCIC)</b> <ul style="list-style-type: none"> <li>• Encouraged open communication and dialogue, collaboration and promotion of inclusive programming on campus.</li> <li>• Created a space where diverse student leaders collaborate and communicate with each other and the SCIC.</li> </ul>

Technology, Open-Source, Programming  
 Paradoxes in Decision Making, Behavioral Finance, Stock  
 Basketball, Traveling, Running

